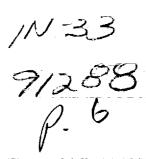
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A 1-W, 30-GHz, CPW Amplifier for ACTS Small Terminal Uplink

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Post Coupler

A CPW-to-CPW post coupler is shown in figure 3. The CPW's share a common ground plane that has an aperture. The coupler is formed by a metal post which passes through the aperture and contacts the strip conductors of the CPW. A pair of wire located to the sides of the post, tie the CPW ground planes to a common potential. The S-parameters for the coupler are shown in figure 4. The coupler works only marginally at 30 GHz, but shows excellent characteristics at 7 GHz. Work is being done, including computer simulations to better understand the behavior of this coupler.

MMIC Chips

Two MMIC chips were used, a three-stage and a single-stage amplifier chip. The gain compression of the three-stage chip is shown in figure 5. A typical chip has a power output of 190 mW, gain of 23 dB, and efficiency of 30.2 percent. Typical characteristics for the single-stage chip are: power output of 710 mW, gain of 4.2 dB, and efficiency of 24 percent. In order to achieve the required 1 W of output power, the MMIC chips were cascaded. The cascading configuration is shown in figure 6.

MMIC Carrier

A novel package, which consist of a carrier and housing, was developed to mount the MMIC chips in the amplifier. The carrier with housing is shown in figure 7. The carrier has CPW interconnects and provides heat-sinking, tuning, and cascading capabilities. The housing provides electrical isolation, mechanical protection, and a feed-through for biasing. Figure 8 shows the measured insertion and return loss of the carrier with a 50- Ω microstrip line in place of the MMIC. After subtracting the losses due to the test fixture, the insertion loss of the carrier is about 1.0 dB and the return loss is better than 15 dB.

Conclusions

The paper presents two schemes for the assembly of a 1-W, 30-GHz MMIC amplifier for the ACTS small terminal. The characteristics of TI MMIC chips, the post coupler, and the carrier have been presented. Future work includes: characterizing the power divider/combiner, tuning the MMIC chips, and assembling the amplifier.

References

- 1. Saunier, P.; and Tserng, H.Q.: AlGaAs/InGaAs Heterostructures with Doped Channels for Discrete Devices and Monolithic Amplifiers. IEEE Trans. Electron Devices, vol. 36, Oct. 1989, pp. 2231-2235.
- 2. Simons, R.N.; and Taub, S.R.: A Flexible CPW Package for a 30-GHz MMIC Amplifier. Presented at the IEEE Topical Meeting on Electrical Performance of Electronic Packaging, Apr. 22-24, 1992, Tuscon, AZ. NASA TM-105630, 1992,

Power input	-25 dBm
Power output	1 W
Center frequency	29.634 GHz
Bandwidth	29.1-30 GHz
Input connector	2.4 mm OS-50
Output waveguide	WR 28

Table 1: Amplifier requirements.

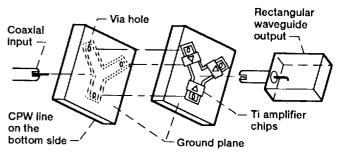
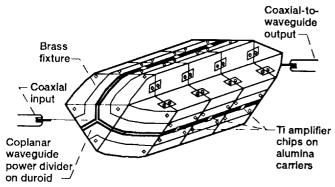


Figure 1.—Amplifier configuration.



(a) Alternate amplifier configuration.

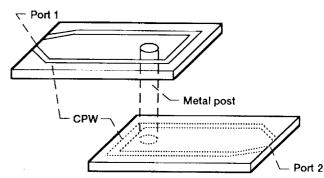
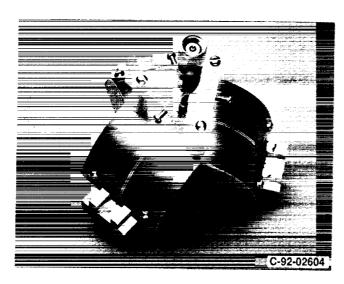


Figure 3.—CPW-to-CPW post coupler.



(b) Coax-to-CPW in-phase three-way radial nonplanar power divider/combiner.

Insertion loss, dB ---50 (a) 0 -10 Return loss, dB -20 -30 -40 0.045 8 40.0 Frequency, GHz

Figure 4.—Post coupler S-parameters.

-10 -20 -30 -40

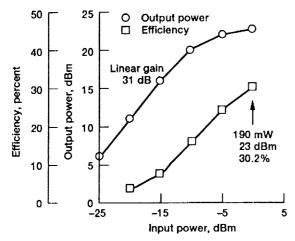
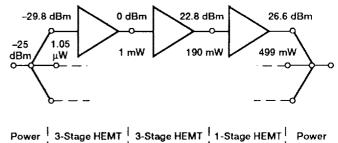


Figure 5.—Gain compression diagram of three-stage amplifier.



divider | Amp | Amp | Amp | combiner 1:3 | 50-100-250 μm | 50-100-250 μm | 800 μm | 3:1 | Gain 30 dB | Gain 23 dB | Gain 4.2 dB |

Figure 6.—MMIC combination scheme.

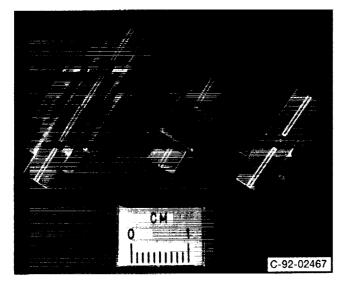


Figure 7.—Carrier with housing.

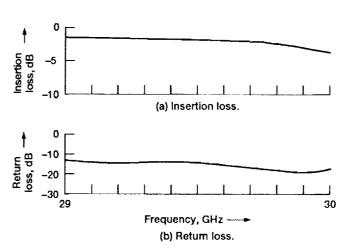


Figure 8.—Measured insertion loss and return loss of the carrier.

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